

CLAIMS

What is claimed is:

- AI
Sub
1. A mold apparatus for forming at least one metal bump for direct placement on bond pads on a secondary substrate, comprising:
- 5 a substrate having a surface;
at least one cavity formed in said surface of said substrate; and
a non-stick protective layer applied to said at least one cavity.
2. The mold apparatus according to claim 1, wherein said non-stick
10 protective layer is a silicon oxide layer.
3. The mold apparatus according to claim 1, wherein said non-stick
protective layer is a silicon nitride layer.
- 15 4. The mold apparatus according to claim 1, wherein said non-stick
protective layer prevents metal material from adhering to said at least one cavity.
5. The mold apparatus according to claim 4, wherein said metal material is a
solder paste comprising lead and nickel.
- 20 6. The mold apparatus according to claim 1, wherein said at least one cavity
has a depth in said surface of said substrate of about 28 micrometers.
- AI
Sub
7. ~~The mold apparatus according to claim 1, wherein said non-stick
25 protective layer has a thickness ranging from about 200 Angstroms to 5 micrometers.~~
8. The mold apparatus according to claim 1, wherein said at least one cavity
has a trapezoidal shape.

9. The mold apparatus according to claim 1, wherein said at least one cavity has a hemispherical shape.

5 10. The mold apparatus according to claim 1, wherein said at least one cavity has a rectangular shape.

11. The mold apparatus according to claim 1, wherein said at least one cavity has a square shape.

10 12. The mold apparatus according to claim 1, further comprising: at least one heating strip located on another surface of said substrate.

13. The mold apparatus according to claim 1, further comprising: a plurality of heating strips located on another surface of said substrate.

15 14. The mold apparatus according to claim 12, further comprising: an electrical conductor connected to a portion of the at least one heating strip.

20 15. The mold apparatus according to claim 13, further comprising: an electrical conductor connected to a portion of the plurality of heating strips.

16. The mold apparatus according to claim 1, wherein said substrate comprises semiconductor material.

25 17. The mold apparatus according to claim 1, wherein said substrate comprises ceramic material.

A3
Sub
18. ~~A solder mold apparatus for forming at least one metal bump for direct placement on a corresponding bond pad on a secondary substrate, comprising:~~

a substrate having a surface;
at least one cavity formed in said surface of said substrate;
a non-stick protective layer applied to said at least one cavity; and
a metal paste applicator.

5

*Wang
Sub
183*

19. The solder mold apparatus according to claim 18, wherein said non-stick protective layer is a silicon oxide layer.

10

20. The solder mold apparatus according to claim 18, wherein said non-stick protective layer is a silicon nitride layer.

21. The solder mold apparatus according to claim 18, wherein said non-stick protective layer prevents metal material from adhering to said at least one cavity.

15

22. The solder mold apparatus according to claim 21, wherein said metal material is a solder paste comprising lead and nickel.

20

23. The solder mold apparatus according to claim 22, further comprising a metal paste dispenser, coupled to said metal paste applicator, to place a metal paste on said substrate.

25

24. The solder mold apparatus according to claim 23, further comprising a heating element to melt said metal paste to form a contact for application to said secondary substrate.

25. The solder mold apparatus according to claim 18, wherein said at least one cavity has a depth in said surface of said substrate of about 28 micrometers.

1008077-2660460

A4
Sub

26. ~~The solder mold apparatus according to claim 18, wherein said non-stick protective layer has a thickness ranging from 200 Angstroms to 5 micrometers.~~

5 27. The solder mold apparatus according to claim 18, wherein said substrate comprises semiconductor material.

28. The solder mold apparatus according to claim 18, wherein said substrate comprises a ceramic material.

10 ~~29. A mold apparatus for forming at least one metal bump for direct placement on bond pads on a secondary substrate, comprising:
a substrate having a surface;
at least one cavity formed in said surface of said substrate, said at least one cavity having
a selected width and a selected length in said surface; and
15 a non-stick protective layer applied to said at least one cavity.~~

30. The mold apparatus according to claim 29, wherein said non-stick protective layer is a silicon oxide layer.

20 31. The mold apparatus according to claim 29, wherein said non-stick protective layer is a silicon nitride layer.

32. The mold apparatus according to claim 29, wherein said non-stick protective layer prevents metal material from adhering to said at least one cavity.

25 33. The mold apparatus according to claim 32, wherein said metal material is a solder paste comprising lead and nickel.

